



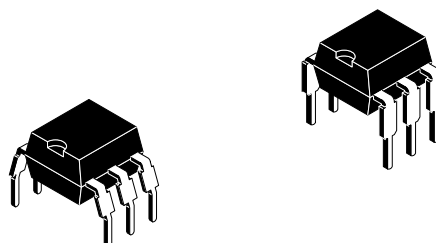
CNY75(G) Series

Vishay Telefunken

Optocoupler with Phototransistor Output

Description

The CNY75(G) series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 6-lead plastic dual in line package. The elements are mounted on one leadframe using a **coplanar technique**, providing a fixed distance between input and output for highest safety requirements.



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Applications

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

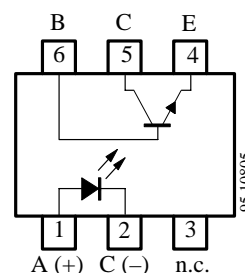
- For appl. class I – IV at mains voltage ≤ 300 V
- For appl. class I – III at mains voltage ≤ 600 V according to VDE 0884, table 2, suitable for:

Switch-mode power supplies, line receiver, computer peripheral interface, microprocessor system interface.

VDE Standards

These couplers perform safety functions according to the following equipment standards:

- **VDE 0884**
Optocoupler for electrical safety requirements
- **IEC 950/EN 60950**
Office machines (applied for reinforced isolation for mains voltage ≤ 400 V_{RMS})
- **VDE 0804**
Telecommunication apparatus and data processing
- **IEC 65**
Safety for mains-operated electronic and related household apparatus



0884

Order Instruction

Ordering Code	CTR Ranking	Remarks
CNY75A/ CNY75GA ¹⁾	63 to 125%	
CNY75B/ CNY75GB ¹⁾	100 to 200%	
CNY75C/ CNY75GC ¹⁾	160 to 320%	
¹⁾ G = Leadform 10.16 mm; G is not market on the body		

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Features

Approvals:

- **BSI:** BS EN 41003, BS EN 60095 (BS 415), BS EN 60950 (BS 7002), Certificate number 7081 and 7402
- **FIMKO (SETI):** EN 60950, Certificate number 12399
- **Underwriters Laboratory (UL)** 1577 recognized, file number E-76222
- **VDE 0884**, Certificate number 94778

VDE 0884 related features:

- Rated impulse voltage (transient overvoltage) $V_{IOTM} = 6$ kV peak
- Isolation test voltage (partial discharge test voltage) $V_{pd} = 1.6$ kV
- Rated isolation voltage (RMS includes DC) $V_{IOWM} = 600$ V_{RMS} (848 V peak)

- Rated recurring peak voltage (repetitive) $V_{IORM} = 600$ V_{RMS}
- Creepage current resistance according to VDE 0303/IEC 112
Comparative Tracking Index: CTI = 275
- Thickness through insulation ≥ 0.75 mm

General features:

- Isolation materials according to UL94-VO
- Pollution degree 2 (DIN/VDE 0110 part 1 resp. IEC 664)
- Climatic classification 55/100/21 (IEC 68 part 1)
- Special construction:
Therefore, extra low coupling capacity of typical 0.3 pF, high **Common Mode Rejection**
- Low temperature coefficient of CTR
- CTR offered in 3 groups
- Coupling System A

Absolute Maximum Ratings

Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V_R	5	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10 \mu s$	I_{FSM}	3	A
Power dissipation	$T_{amb} \leq 25^\circ C$	P_V	100	mW
Junction temperature		T_j	125	$^\circ C$

Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector base voltage		V_{CBO}	90	V
Collector emitter voltage		V_{CEO}	90	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10$ ms	I_{CM}	100	mA
Power dissipation	$T_{amb} \leq 25^\circ C$	P_V	150	mW
Junction temperature		T_j	125	$^\circ C$

Coupler

Parameter	Test Conditions	Symbol	Value	Unit
AC isolation test voltage (RMS)	$t = 1$ min	V_{IO}	3.75	kV
Total power dissipation	$T_{amb} \leq 25^\circ C$	P_{tot}	250	mW
Ambient temperature range		T_{amb}	-55 to +100	$^\circ C$
Storage temperature range		T_{stg}	-55 to +125	$^\circ C$
Soldering temperature	2 mm from case, $t \leq 10$ s	T_{sd}	260	$^\circ C$



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Electrical Characteristics ($T_{amb} = 25^{\circ}\text{C}$)

Input (Emitter)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 50 \text{ mA}$	V_F		1.25	1.6	V
Reverse current	$V_R = 6 \text{ V}$	I_R			10	μA
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	C_j		50		pF

Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector base voltage	$I_C = 100 \mu\text{A}$	V_{CB0}	90			V
Collector emitter voltage	$I_C = 1 \text{ mA}$	V_{CEO}	90			V
Emitter collector voltage	$I_E = 100 \mu\text{A}$	V_{ECO}	7			V
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0$	I_{CEO}			150	nA

Coupler

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V_{CEsat}			0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega$	f_c		110		kHz
Coupling capacitance	$f = 1 \text{ MHz}$	C_k		0.3		pF

Current Transfer Ratio (CTR)

Parameter	Test Conditions	Type	Symbol	Min.	Typ.	Max.	Unit
I_C/I_F	$V_{CE} = 5 \text{ V}, I_F = 1 \text{ mA}$	CNY75(G)A	CTR	0.15			
		CNY75(G)B	CTR	0.3			
		CNY75(G)C	CTR	0.6			
	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	CNY75(G)A	CTR	0.63		1.25	
		CNY75(G)B	CTR	1		2	
		CNY75(G)C	CTR	1.6		3.2	

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Maximum Safety Ratings (according to VDE 0884) see figure 1

This device is used for protective separation against electrical shock only within the maximum safety ratings. This must be ensured by using protective circuits in the applications.

Input (Emitter)

Parameters	Test Conditions	Symbol	Value	Unit
Forward current		I_{si}	130	mA

Output (Detector)

Parameters	Test Conditions	Symbol	Value	Unit
Power dissipation	$T_{amb} \leq 25^{\circ}\text{C}$	P_{si}	265	mW

Coupler

Parameters	Test Conditions	Symbol	Value	Unit
Rated impulse voltage		V_{IOTM}	6	kV
Safety temperature		T_{si}	150	$^{\circ}\text{C}$

Insulation Rated Parameters (according to VDE 0884)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Partial discharge test voltage – Routine test	100%, $t_{test} = 1\text{ s}$	V_{pd}	1.6			kV
Partial discharge test voltage – Lot test (sample test)	$t_{Tr} = 60\text{ s}$, $t_{test} = 10\text{ s}$, (see figure 2)	V_{IOTM}	6			kV
		V_{pd}	1.3			kV
Insulation resistance	$V_{IO} = 500\text{ V}$	R_{IO}	10^{12}			Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} \leq 100^{\circ}\text{C}$	R_{IO}	10^{11}			Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} \leq 150^{\circ}\text{C}$ (construction test only)	R_{IO}	10^9			Ω

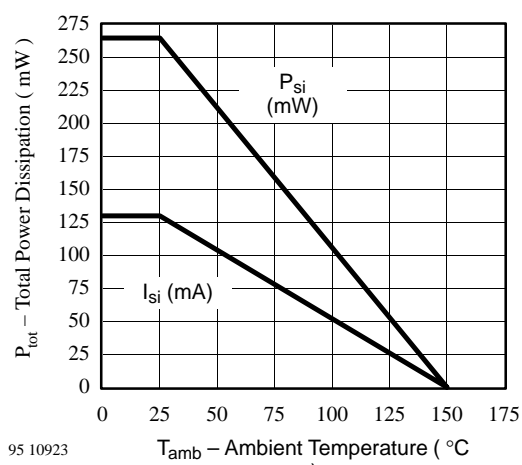


Figure 1. Derating diagram

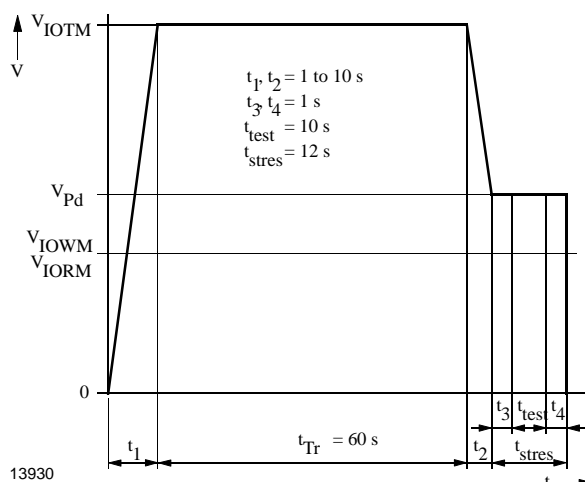


Figure 2. Test pulse diagram for sample test according to DIN VDE 0884



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Switching Characteristics of CNY75(G)A

Parameter	Test Conditions	Symbol	Typ.	Unit
Delay time	$V_S = 5\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\ \Omega$ (see figure 3)	t_d	2.0	μs
Rise time		t_r	2.5	μs
Fall time		t_f	2.7	μs
Storage time		t_s	0.3	μs
Turn-on time		t_{on}	4.5	μs
Turn-off time		t_{off}	3.0	μs
Turn-on time	$V_S = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 1\text{ k}\Omega$ (see figure 4)	t_{on}	10.0	μs
Turn-off time		t_{off}	25.0	μs

Switching Characteristics of CNY75(G)B

Parameter	Test Conditions	Symbol	Typ.	Unit
Delay time	$V_S = 5\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\ \Omega$ (see figure 3)	t_d	2.5	μs
Rise time		t_r	3.0	μs
Fall time		t_f	3.7	μs
Storage time		t_s	0.3	μs
Turn-on time		t_{on}	5.5	μs
Turn-off time		t_{off}	4.0	μs
Turn-on time	$V_S = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 1\text{ k}\Omega$ (see figure 4)	t_{on}	16.5	μs
Turn-off time		t_{off}	20	μs

Switching Characteristics of CNY75(G)C

Parameter	Test Conditions	Symbol	Typ.	Unit
Delay time	$V_S = 5\text{ V}$, $I_C = 10\text{ mA}$, $R_L = 100\ \Omega$ (see figure 3)	t_d	2.8	μs
Rise time		t_r	4.2	μs
Fall time		t_f	4.7	μs
Storage time		t_s	0.3	μs
Turn-on time		t_{on}	7.0	μs
Turn-off time		t_{off}	5.0	μs
Turn-on time	$V_S = 5\text{ V}$, $I_F = 10\text{ mA}$, $R_L = 1\text{ k}\Omega$ (see figure 4)	t_{on}	11	μs
Turn-off time		t_{off}	37.5	μs

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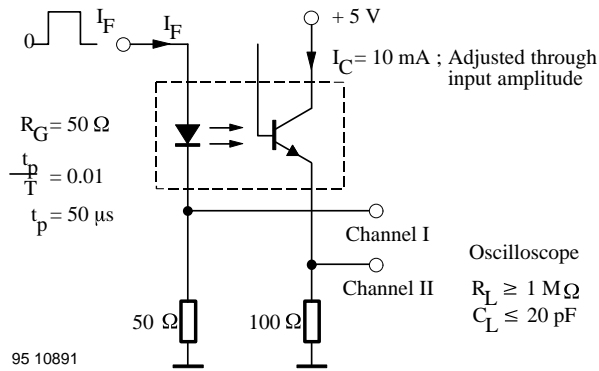


Figure 3. Test circuit, non-saturated operation

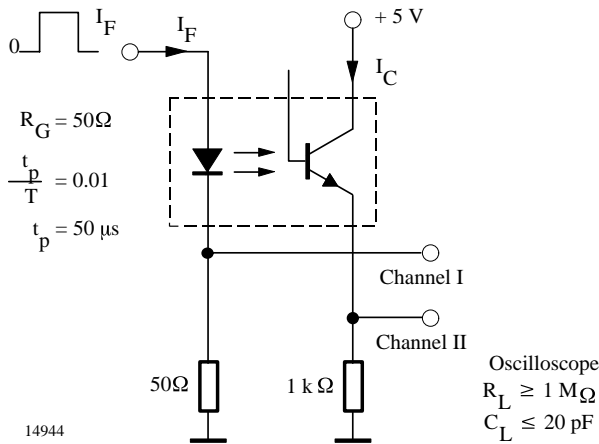


Figure 4. Test circuit, saturated operation

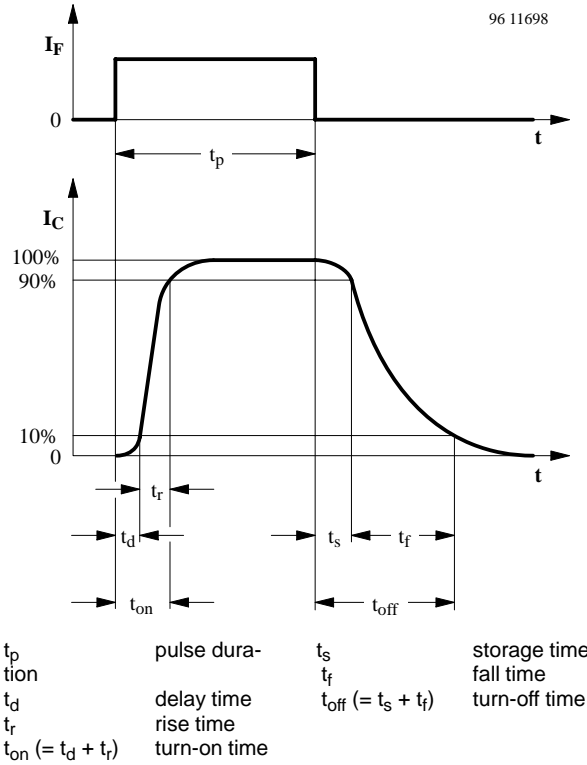


Figure 5. Switching times

Typical Characteristics ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)

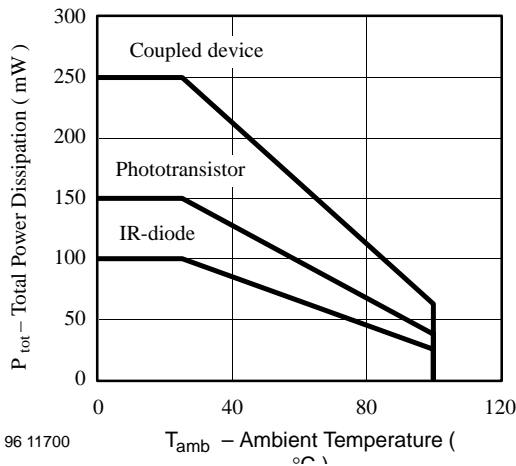


Figure 6. Total Power Dissipation vs. Ambient Temperature

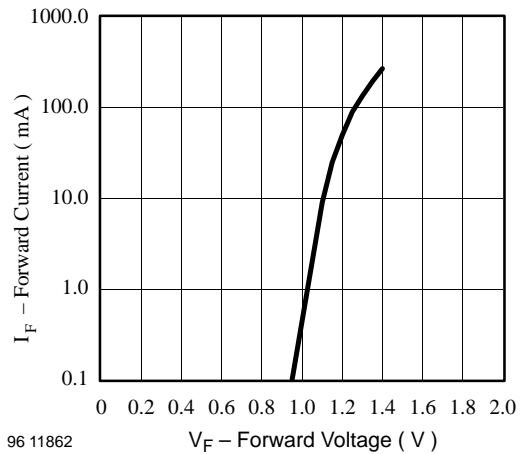
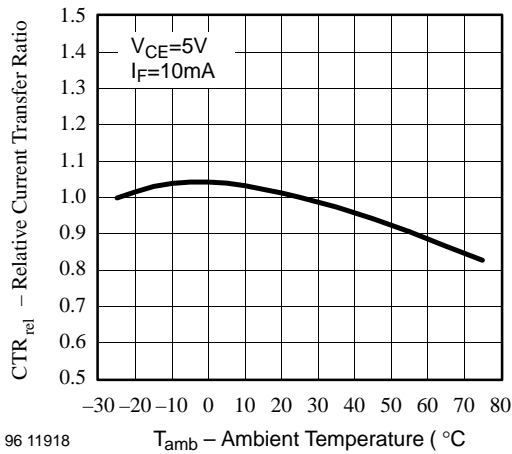


Figure 7. Forward Current vs. Forward Voltage

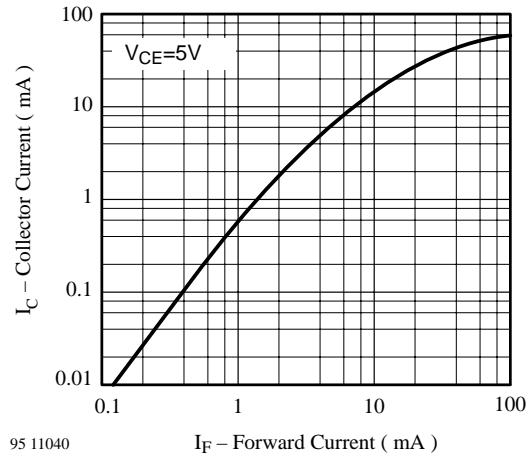


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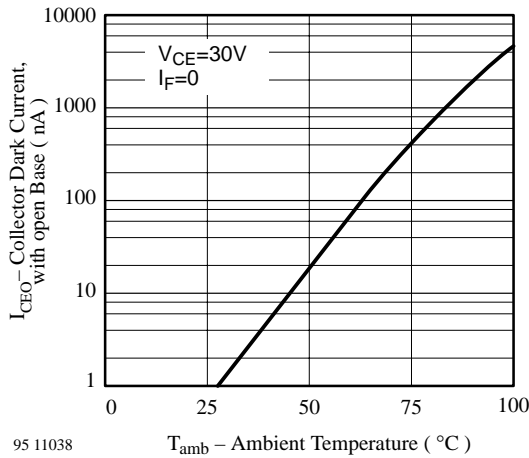
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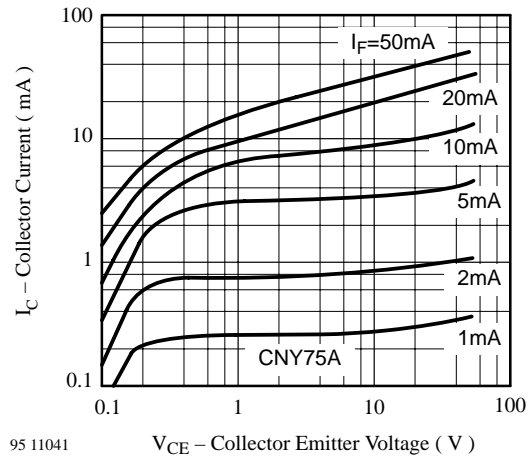
96 11918
Figure 8. Relative Current Transfer Ratio vs. Ambient Temperature



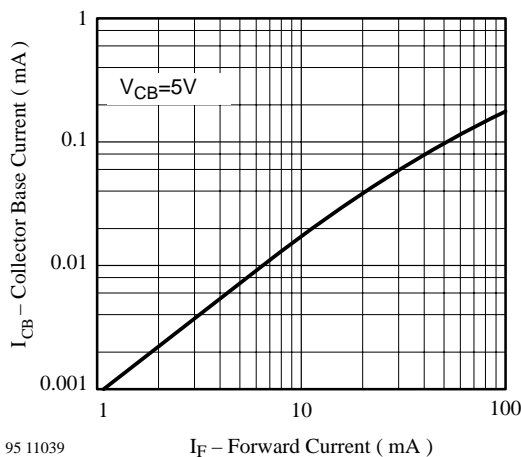
95 11040
Figure 11. Collector Current vs. Forward Current



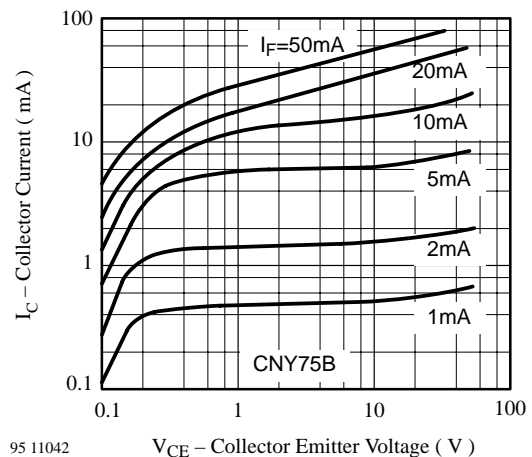
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Figure 9. Collector Dark Current vs. Ambient Temperature



95 11041
Figure 12. Collector Current vs. Collector Emitter Voltage



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Figure 10. Collector Base Current vs. Forward Current



95 11042
Figure 13. Collector Current vs. Collector Emitter Voltage

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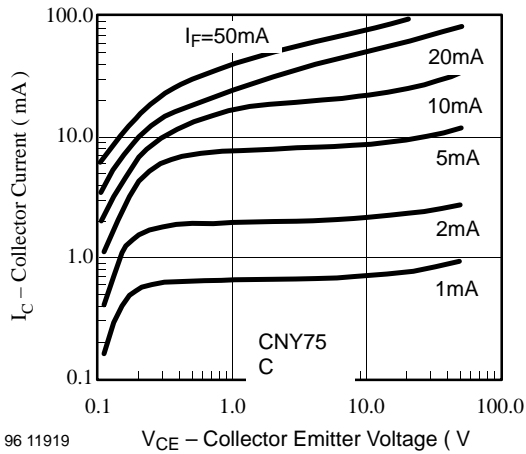


Figure 14. Collector Current vs. Collector Emitter Voltage

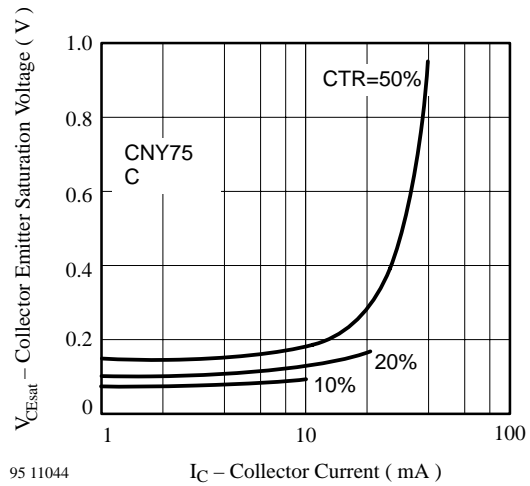


Figure 17. Coll. Emitter Sat. Voltage vs. Coll. Current

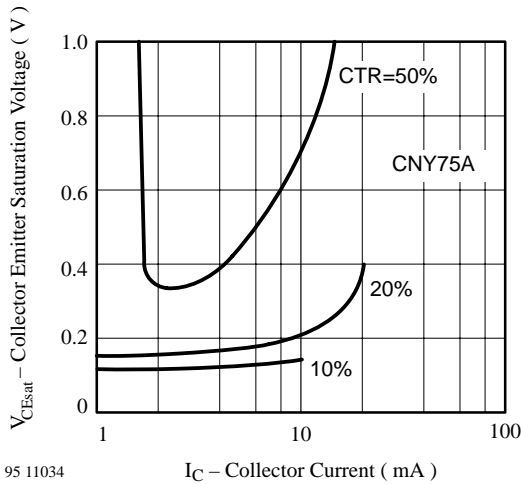


Figure 15. Coll. Emitter Sat. Voltage vs. Coll. Current

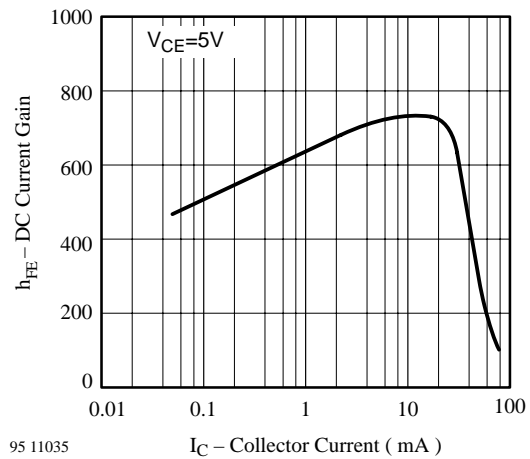


Figure 18. DC Current Gain vs. Collector Current

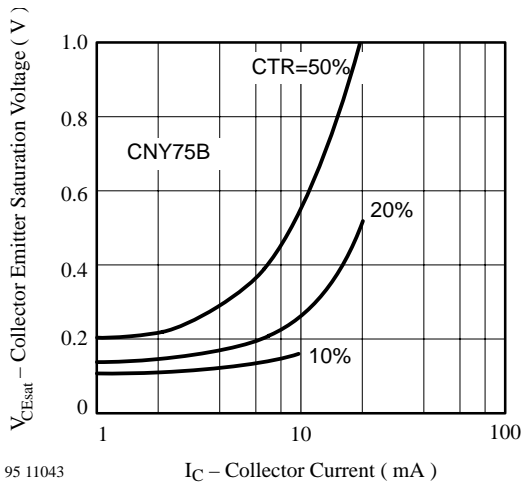


Figure 16. Coll. Emitter Sat. Voltage vs. Coll. Current

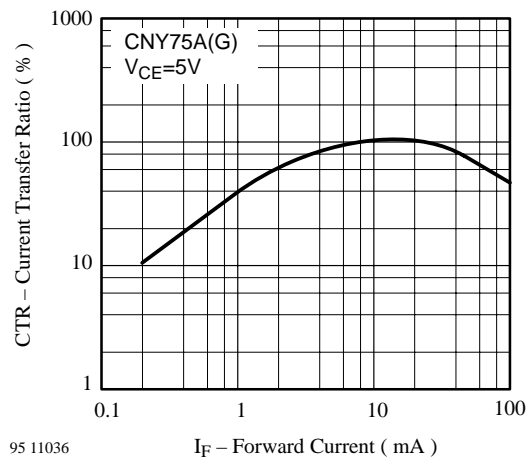


Figure 19. Current Transfer Ratio vs. Forward Current



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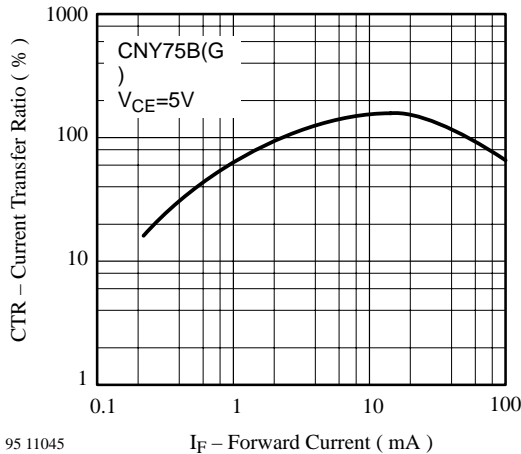


Figure 20. Current Transfer Ratio vs. Forward Current

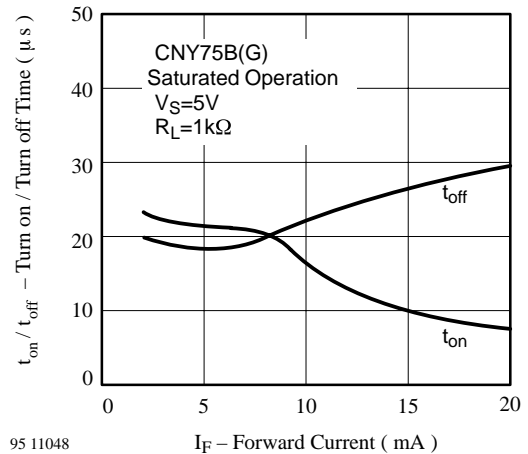


Figure 23. Turn on / off Time vs. Forward Current

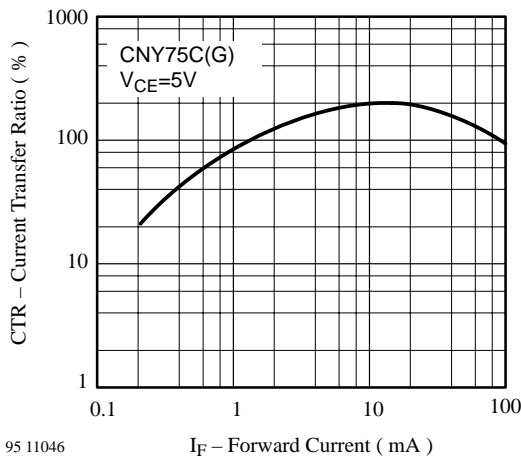


Figure 21. Current Transfer Ratio vs. Forward Current

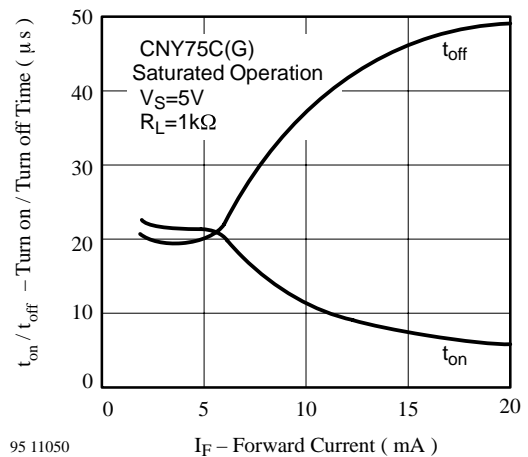


Figure 24. Turn on / off Time vs. Forward Current

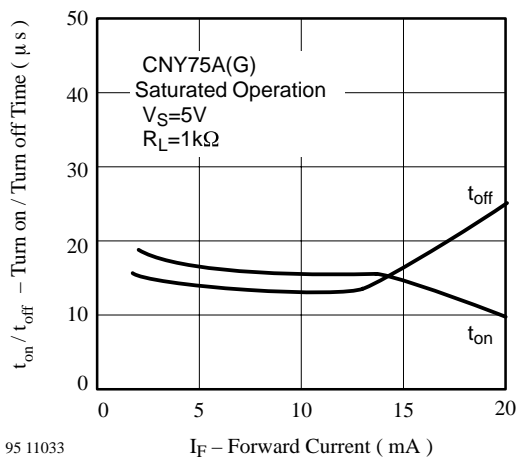


Figure 22. Turn on / off Time vs. Forward Current

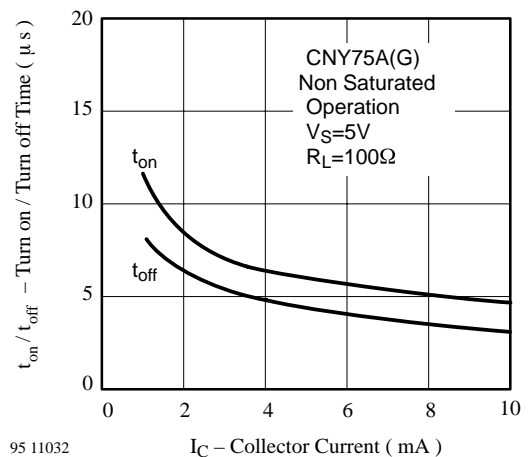


Figure 25. Turn on / off Time vs. Collector Current

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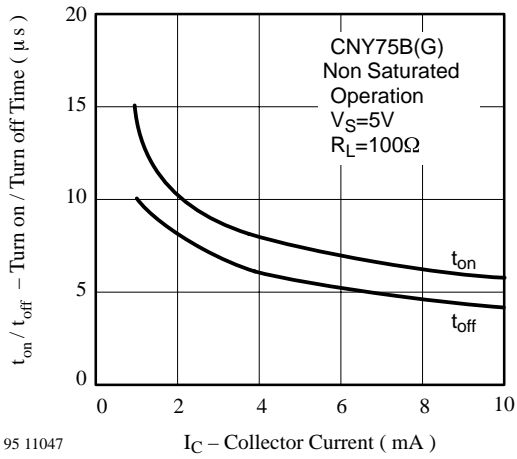


Figure 26. Turn on / off Time vs. Collector Current

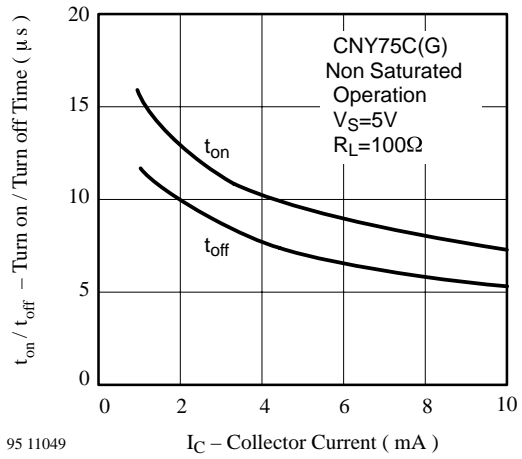


Figure 27. Turn on / off Time vs. Collector Current

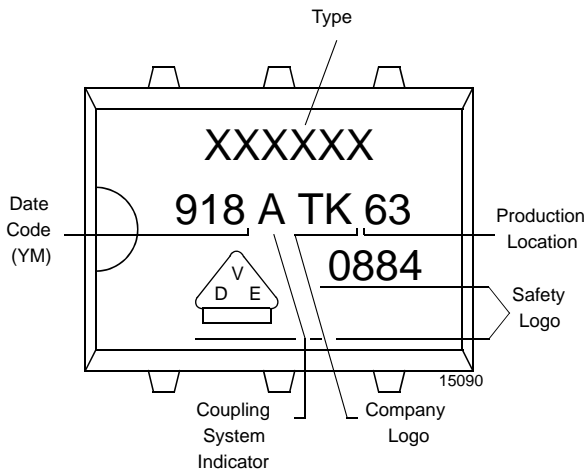


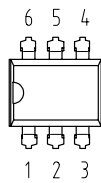
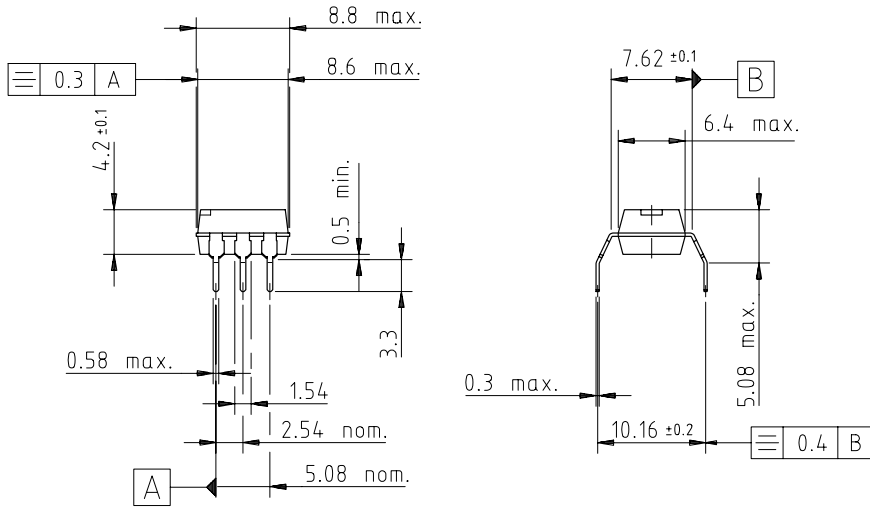
Figure 28. Marking example



CNY75(G) Series

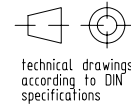
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Dimensions of CNY75G in mm



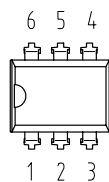
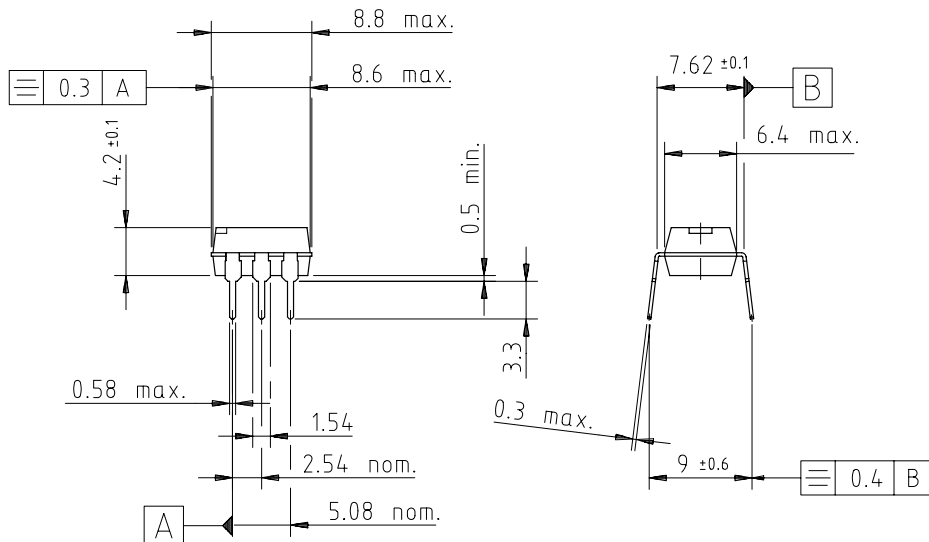
weight: ca. 0.50 g
 creepage distance: \cong 8 mm
 air path: \cong 8 mm

after mounting on PC board



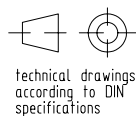
14771

Dimensions of CNY75 in mm



weight: 0.50 g
 creepage distance: \cong 6 mm
 air path: \cong 6 mm

after mounting on PC board



14770